

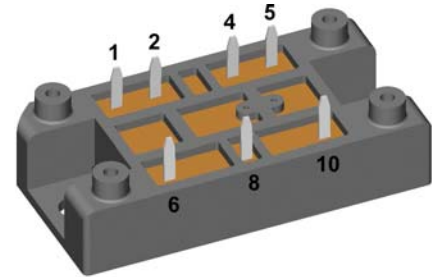
# Standard Rectifier Module

| 3~<br>Rectifier |          |
|-----------------|----------|
| $V_{RRM}$       | = 1600 V |
| $I_{DAV}$       | = 80 A   |
| $I_{FSM}$       | = 600 A  |

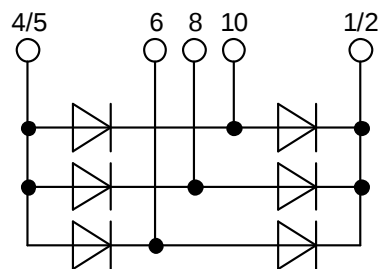
## 3~ Rectifier Bridge

Part number

**VUO80-16NO1**



 E72873



### Features / Advantages:

- Package with DCB ceramic
- Reduced weight
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

### Applications:

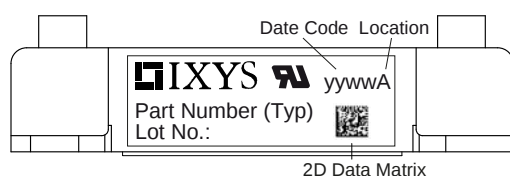
- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: V1-A-Pack

- Isolation Voltage: 3600V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Height: 17 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

| Rectifier  |                                              |                                                   |                                                     | Ratings                        |      |      |                   |
|------------|----------------------------------------------|---------------------------------------------------|-----------------------------------------------------|--------------------------------|------|------|-------------------|
| Symbol     | Definition                                   | Conditions                                        |                                                     | min.                           | typ. | max. | Unit              |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$                     |                                                     |                                |      | 1700 | V                 |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$                     |                                                     |                                |      | 1600 | V                 |
| $I_R$      | reverse current                              | $V_R = 1600\text{ V}$                             | $T_{VJ} = 25^{\circ}\text{C}$                       |                                |      | 40   | $\mu\text{A}$     |
|            |                                              | $V_R = 1600\text{ V}$                             | $T_{VJ} = 150^{\circ}\text{C}$                      |                                |      | 1.5  | mA                |
| $V_F$      | forward voltage drop                         | $I_F = 30\text{ A}$                               | $T_{VJ} = 25^{\circ}\text{C}$                       |                                |      | 1.14 | V                 |
|            |                                              | $I_F = 90\text{ A}$                               |                                                     |                                |      | 1.48 | V                 |
|            |                                              | $I_F = 30\text{ A}$                               | $T_{VJ} = 125^{\circ}\text{C}$                      |                                |      | 1.06 | V                 |
|            |                                              | $I_F = 90\text{ A}$                               |                                                     |                                |      | 1.51 | V                 |
| $I_{DAV}$  | bridge output current                        | $T_C = 110^{\circ}\text{C}$<br>rectangular        | $T_{VJ} = 150^{\circ}\text{C}$<br>$d = \frac{1}{3}$ |                                |      | 80   | A                 |
| $V_{FO}$   | threshold voltage                            | } for power loss calculation only                 |                                                     | $T_{VJ} = 150^{\circ}\text{C}$ |      | 0.81 | V                 |
| $r_F$      | slope resistance                             |                                                   |                                                     |                                |      | 7.8  | m $\Omega$        |
| $R_{thJC}$ | thermal resistance junction to case          |                                                   |                                                     |                                |      | 1.1  | K/W               |
| $R_{thCH}$ | thermal resistance case to heatsink          |                                                   |                                                     |                                | 0.3  |      | K/W               |
| $P_{tot}$  | total power dissipation                      | $T_C = 25^{\circ}\text{C}$                        |                                                     |                                |      | 110  | W                 |
| $I_{FSM}$  | max. forward surge current                   | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$  | $T_{VJ} = 45^{\circ}\text{C}$                       |                                |      | 600  | A                 |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$                                  |                                |      | 650  | A                 |
|            |                                              | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$  | $T_{VJ} = 150^{\circ}\text{C}$                      |                                |      | 510  | A                 |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$                                  |                                |      | 550  | A                 |
| $I^2t$     | value for fusing                             | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$  | $T_{VJ} = 45^{\circ}\text{C}$                       |                                |      | 1.80 | kA <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$                                  |                                |      | 1.76 | kA <sup>2</sup> s |
|            |                                              | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$  | $T_{VJ} = 150^{\circ}\text{C}$                      |                                |      | 1.30 | kA <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$                                  |                                |      | 1.26 | kA <sup>2</sup> s |
| $C_J$      | junction capacitance                         | $V_R = 400\text{ V}; f = 1\text{ MHz}$            |                                                     |                                | 18   |      | pF                |

| Package V1-A-Pack |                                                              |                      | Ratings |      |      |      |
|-------------------|--------------------------------------------------------------|----------------------|---------|------|------|------|
| Symbol            | Definition                                                   | Conditions           | min.    | typ. | max. | Unit |
| $I_{RMS}$         | RMS current                                                  | per terminal         |         |      | 100  | A    |
| $T_{stg}$         | storage temperature                                          |                      | -40     |      | 125  | °C   |
| $T_{VJ}$          | virtual junction temperature                                 |                      | -40     |      | 150  | °C   |
| Weight            |                                                              |                      |         | 37   |      | g    |
| $M_D$             | mounting torque                                              |                      | 2       |      | 2.5  | Nm   |
| $d_{Spp/App}$     | creepage distance on surface   striking distance through air | terminal to terminal | 6.0     |      |      | mm   |
| $d_{Spb/Apb}$     |                                                              | terminal to backside | 12.0    |      |      | mm   |
| $V_{ISOL}$        | isolation voltage                                            | t = 1 second         | 3600    |      |      | V    |
|                   |                                                              | t = 1 minute         | 3000    |      |      | V    |

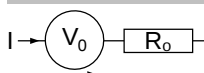


| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-------------|--------------------|---------------|----------|----------|
| Standard | VUO80-16NO1 | VUO80-16NO1        | Box           | 10       | 469173   |

### Equivalent Circuits for Simulation

\* on die level

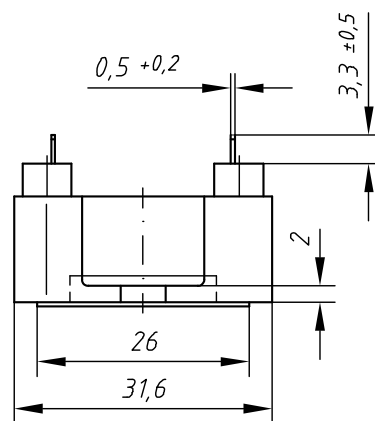
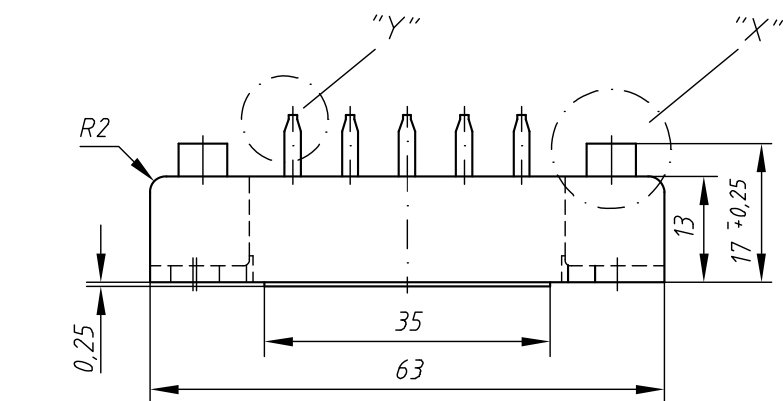
$T_{VJ} = 150^{\circ}\text{C}$



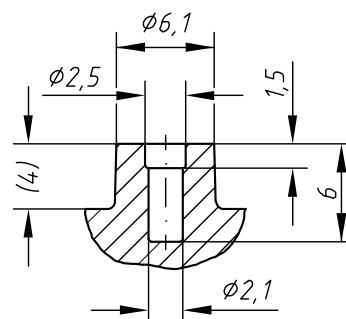
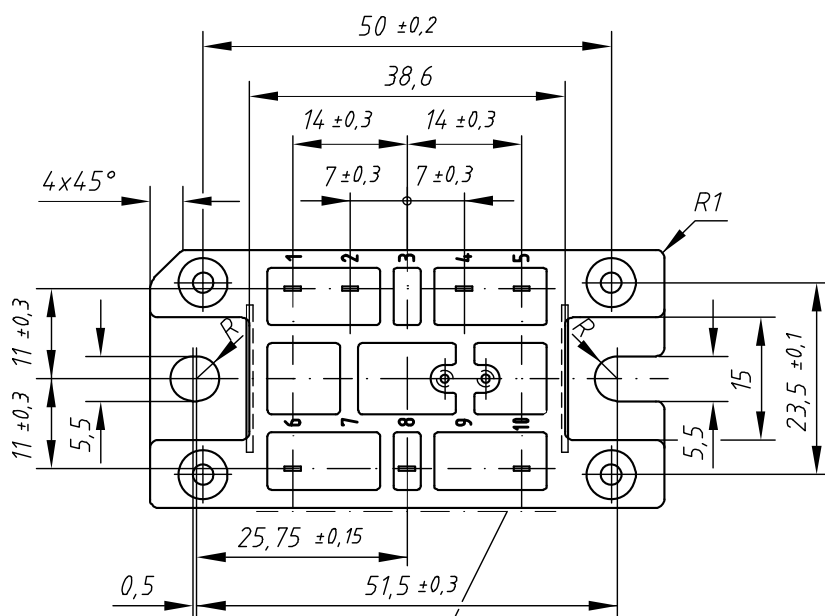
Rectifier

|             |                    |      |    |
|-------------|--------------------|------|----|
| $V_{0\max}$ | threshold voltage  | 0.81 | V  |
| $R_{0\max}$ | slope resistance * | 6.6  | mΩ |

## Outlines V1-A-Pack

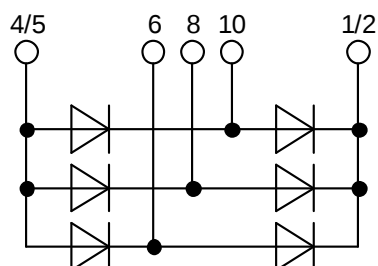


Detail "X" M 2:1



Detail "Y" M 5:1

Aufdruck der Typenbezeichnung



## Rectifier

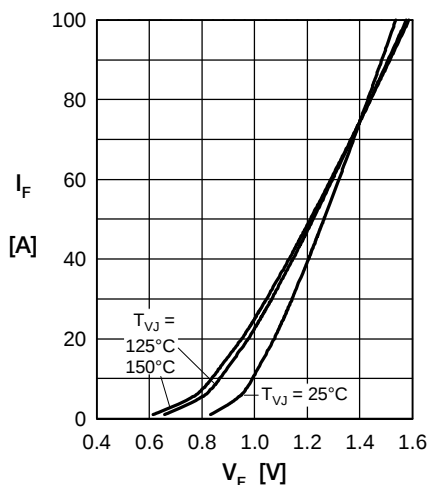


Fig. 1 Forward current vs. voltage drop per diode

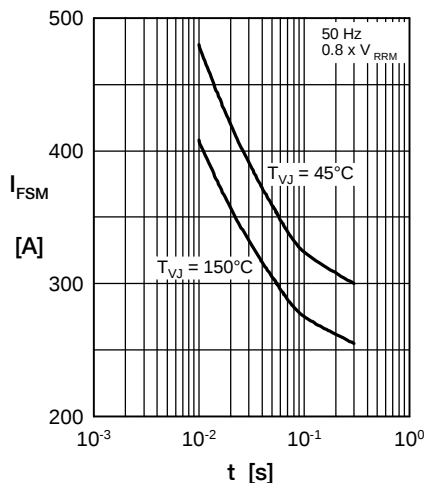


Fig. 2 Surge overload current vs. time per diode

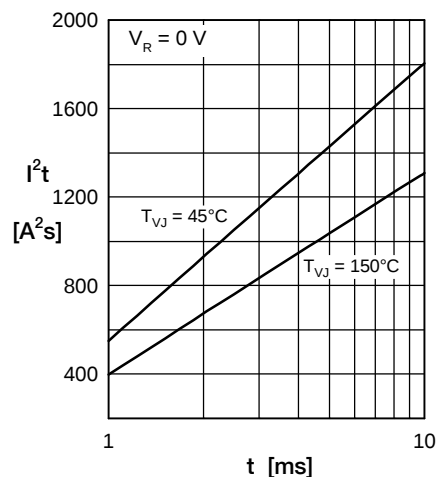


Fig. 3  $I^2t$  vs. time per diode

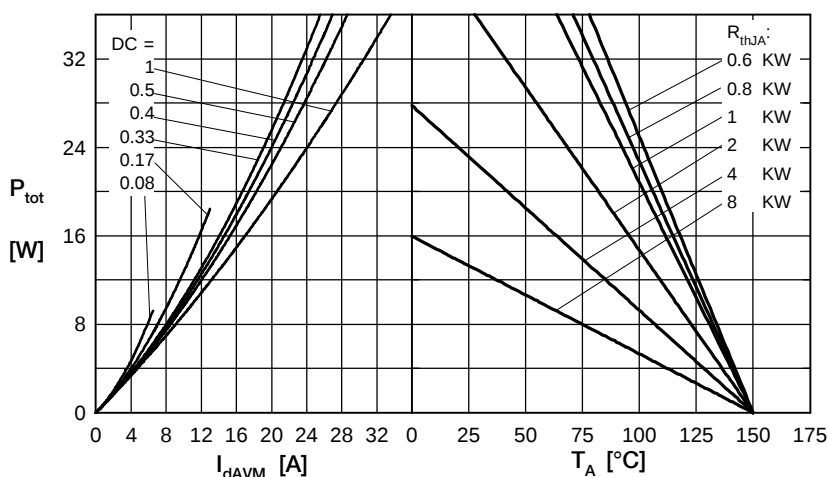


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

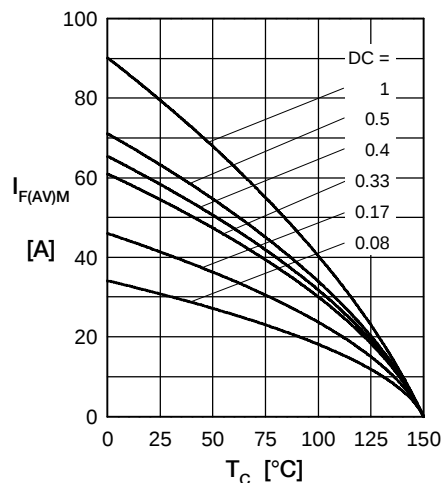


Fig. 5 Max. forward current vs. case temperature per diode

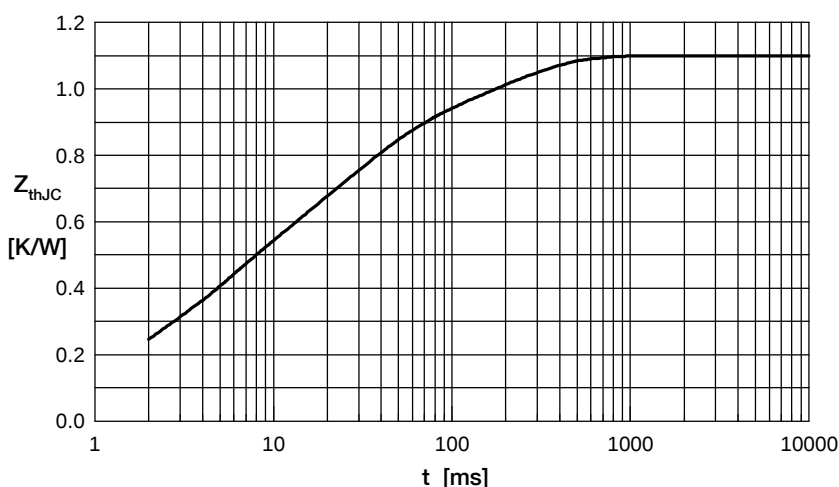


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for  $Z_{thJC}$  calculation:

| i | $R_{th}$ (K/W) | $t_i$ (s) |
|---|----------------|-----------|
| 1 | 0.0607         | 0.0004    |
| 2 | 0.1230         | 0.00256   |
| 3 | 0.2305         | 0.0045    |
| 4 | 0.4230         | 0.0242    |
| 5 | 0.2628         | 0.1800    |

# AMEYA360

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